

50 V, 100 mA PNP resistor-equipped transistor; R1 = 4.7 k $\Omega$ , R2 = open

26 May 2025

**Product data sheet** 

## 1. General description

PNP Resistor-Equipped Transistor (RET) in a leadless ultra small DFN1006B-3 (SOT883B) Surface-Mounted Device (SMD) plastic package.

NPN complement: PDTC143TMB

### 2. Features and benefits

- · 100 mA output current capability
- Reduces component count
- Built-in bias resistors
- Reduces pick and place costs
- Simplifies circuit design
- · Leadless ultra small SMD plastic package
- Low package height of 0.37 mm
- AEC-Q101 qualified

## 3. Applications

- · Low-current peripheral driver
- Control of IC inputs
- Replaces general-purpose transistors in digital applications
- Mobile applications

### 4. Quick reference data

### Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	-50	V
Io	output current		-	-	-100	mA
R1	bias resistor 1 (input)	T <sub>amb</sub> = 25 °C	3.3	4.7	6.1	kΩ



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# 5. Pinning information

**Table 2. Pinning information** 

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	I	input (base)	3	
2	G	GND (emitter)		
3	0	output (collector)	Transparent top view DFN1006B-3 (SOT883B)	R1 GND aaa-039619

# 6. Ordering information

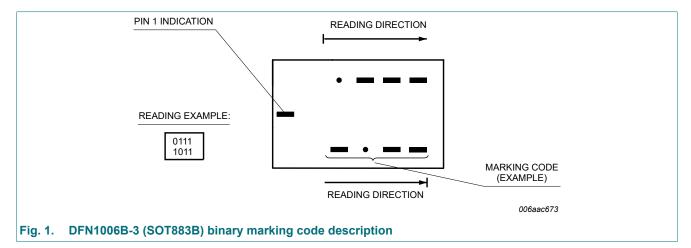
**Table 3. Ordering information** 

Type number	Package	ackage					
	Name	Description	Version				
PDTA143TMB		plastic, leadless ultra small plastic package; 3 solder lands; 0.35 mm pitch; 1.0 mm x 0.6 mm x 0.37 mm body	SOT883B				

# 7. Marking

Table 4. Marking codes

Type number	Marking code
PDTA143TMB	0010
	1000



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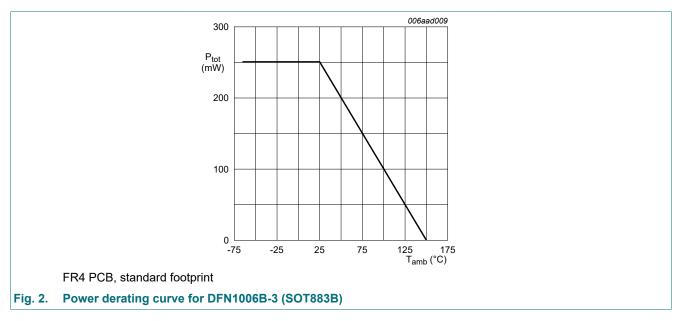
# 8. Limiting values

### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter		-	-50	V
$V_{CEO}$	collector-emitter voltage	open base		-	-50	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	-5	V
Io	output current			-	-100	mA
I <sub>CM</sub>	peak collector current	t <sub>p</sub> ≤ 1 ms; pulsed		-	-100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	250	mW
T <sub>j</sub>	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-65	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



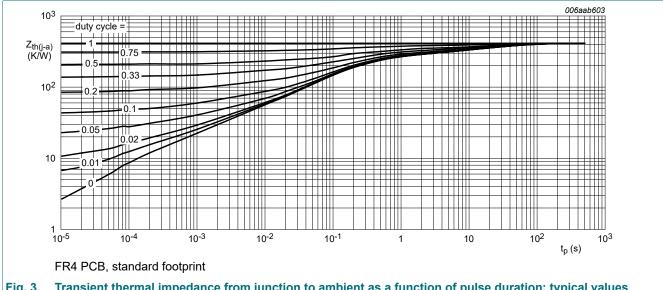
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## 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1]	-	-	500	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.



Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

### 10. Characteristics

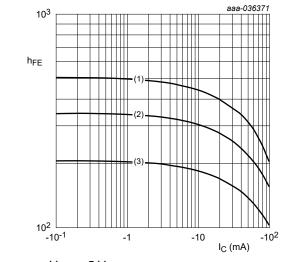
**Table 7. Characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off current	V <sub>CB</sub> = -50 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	-100	nA
I <sub>CEO</sub>	collector-emitter cut-off	V <sub>CE</sub> = -30 V; I <sub>B</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	-100	nA
	current	V <sub>CE</sub> = -30 V; I <sub>B</sub> = 0 A; T <sub>j</sub> = 150 °C		-	-	-5	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = -5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	-100	nA
h <sub>FE</sub>	DC current gain	$V_{CE}$ = -5 V; $I_{C}$ = -1 mA; $T_{amb}$ = 25 °C		200	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	C = -5 mA; I <sub>B</sub> = -0.25 mA; T <sub>amb</sub> = 25 °C		-	-	-150	mV
R1	bias resistor 1 (input)	T <sub>amb</sub> = 25 °C		3.3	4.7	6.1	kΩ
C <sub>c</sub>	collector capacitance	$V_{CB}$ = -10 V; $I_{E}$ = 0 A; $i_{e}$ = 0 A; $f$ = 1 MHz; $T_{amb}$ = 25 °C		-	-	3	pF
f <sub>T</sub>	transition frequency	$V_{CE}$ = -5 V; $I_{C}$ = -10 mA; f = 100 MHz; $T_{amb}$ = 25 °C	[1]	-	180	-	MHz

Characteristics of built-in transistor.

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### 50 V, 100 mA PNP resistor-equipped transistor; R1 = 4.7 k $\Omega$ , R2 = open

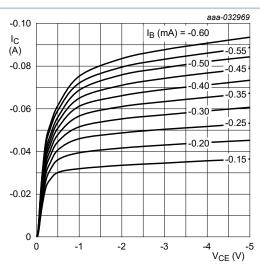


 $V_{CE} = -5 V$ 

 $(1) T_{amb} = 100 °C$ 

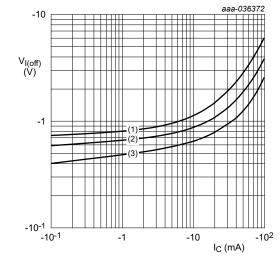
(2)  $T_{amb} = 25 \,^{\circ}\text{C}$ (3)  $T_{amb} = -40 \,^{\circ}\text{C}$ 

Fig. 4. DC current gain as a function of collector current; typical values



T<sub>amb</sub> = 25 °C

Fig. 5. Collector current as a function of collectoremitter voltage; typical values



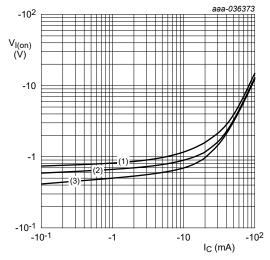
 $V_{CE} = -5 V$ 

(1)  $T_{amb} = -40 \, ^{\circ}C$ 

(2)  $T_{amb} = 25 \, ^{\circ}C$ 

(3)  $T_{amb} = 100 \, ^{\circ}C$ 

Fig. 6. Off-state input voltage as a function of collector | Fig. 7. current; typical values



 $V_{CE} = -0.3 \text{ V}$ 

(1) T<sub>amb</sub> = - 40 °C (2) T<sub>amb</sub> = 25 °C

(3)  $T_{amb} = 100 \, ^{\circ}C$ 

On-state input voltage as a function of collector current; typical values

### 50 V, 100 mA PNP resistor-equipped transistor; R1 = 4.7 k $\Omega$ , R2 = open

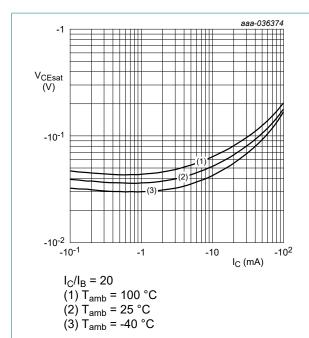


Fig. 8. Collector-emitter saturation voltage as a function of collector current; typical values

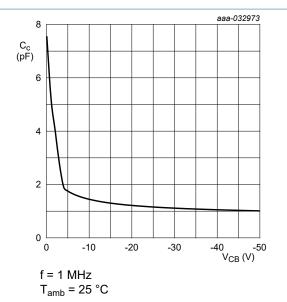


Fig. 9. Collector capacitance as a function of collectorbase voltage; typical values

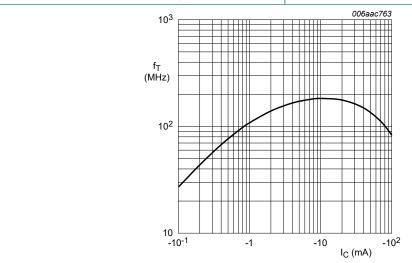


Fig. 10. Transition frequency as a function of collector current; typical values of built-in transistor

50 V, 100 mA PNP resistor-equipped transistor; R1 = 4.7 k $\Omega$ , R2 = open

## 11. Test information

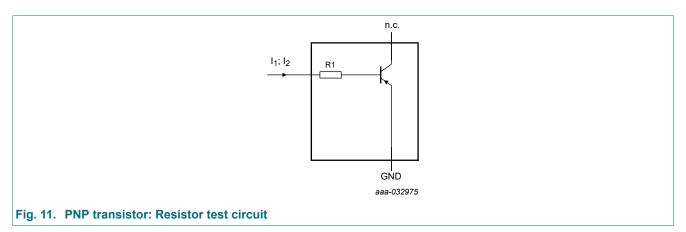
### **Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

#### **Resistor calculation**

· Calculation of bias resistor 1 (R1)

$$R_{I} = \frac{V(I_{2}) - V(I_{I})}{I_{2} - I_{I}}$$

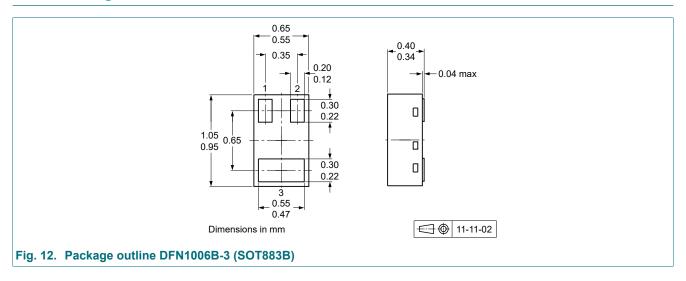


#### **Resistor test conditions**

**Table 8. Resistor test conditions** 

Type number	R1 (kΩ)	R2 (kΩ)	Test conditions			
			I <sub>1</sub>	l <sub>2</sub>	l <sub>3</sub>	l <sub>4</sub>
PDTA143TMB	4.7	open	-600 μΑ	-700 μA	-	-

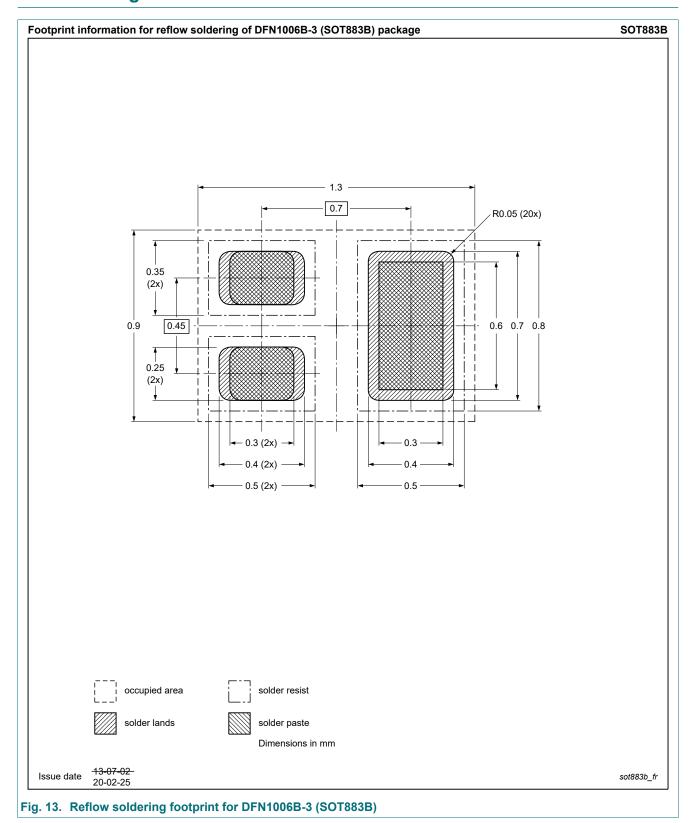
# 12. Package outline



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50 V, 100 mA PNP resistor-equipped transistor; R1 = 4.7 k $\Omega$ , R2 = open

# 13. Soldering



50 V, 100 mA PNP resistor-equipped transistor; R1 = 4.7 k $\Omega$ , R2 = open

# 14. Revision history

### Table 9. Revision history

Table 3. INEVISION MISTOR	y				
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes	
PDTA143TMB v.3	20250526	Product data sheet	-	PDTA143TMB v.2	
Modification:	of Nexperia. Legal texts l Characterist	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Characteristics: Graphs added/replaced</li> <li>Test information expanded</li> </ul>			
PDTA143TMB v.2	20120504	Product data sheet	-	PDTA143TMB v.1	
PDTA143TMB v.1	20122504	Product data sheet	-	-	

### 50 V, 100 mA PNP resistor-equipped transistor; R1 = 4.7 k $\Omega$ , R2 = open

## 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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PDTA143TMB

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